

60V N-Channel MOSFET



TO-92

5

Pin Definition:

- 1. Source
- 2. Gate
- 3. Drain

PRODUCT SUMMARY

V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (mA)		
60	5 @ V _{GS} = 10V	100		
	5.5 @ V _{GS} = 5V	100		

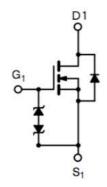
Features

- Low On-Resistance
- ESD Protection
- High Speed Switching
- Low Voltage Drive

Ordering Information

Part No.	Package	Packing
TSM2N7000KCT B0	TO-92	1Kpcs / Bulk
TSM2N7000KCT A3	TO-92	2Kpcs / Ammo

Block Diagram



N-Channel MOSFET

Absolute Maximum Rating (Ta = 25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit		
Drain-Source Voltage		V _{DS}	60	V	
Gate-Source Voltage		V_{GS}	±20	V	
D : 0	Continuous @ T _A =25°C	I _D	300	mA	
Drain Current	Pulsed	I _{DM}	700		
Duris Danson O sussi	Continuous @ T _A =25°C	I _{DR}	300	mA	
Drain Reverse Current	Pulsed	I _{DMR}	700		
Maximum Power Dissipation		P_{D}	400	mW	
Operating Junction Temperature		TJ	+150	°C	
Operating Junction and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C	

Thermal Performance

Parameter	Symbol	Limit	Unit
Lead Temperature (1/8" from case)	T_L	10	S
Junction to Ambient Thermal Resistance (PCB mounted)	$R\Theta_{JA}$	357	°C/W

Notes:

- a. Pulse width limited by the Maximum junction temperature
- b. Surface Mounted on FR4 Board, t ≤ 5 sec.



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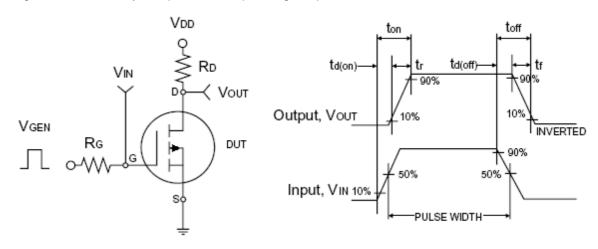


Electrical Specifications (Ta = 25°C, unless otherwise noted)

Parameter	Conditions	Symbol	Min	Тур	Max	Unit
Static						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 10\mu A$	BV _{DSS}	60			V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	V _{GS(TH)}	1.0		2.5	V
Gate Body Leakage	$V_{GS} = \pm 20V, V_{DS} = 0V$	I _{GSS}			±10	uA
Zero Gate Voltage Drain Current	$V_{DS} = 60V, V_{GS} = 0V$	I _{DSS}			1.0	uA
Danier Courses On Otata Desistance	Drain-Source On-State Resistance		3	5	Ω	
Drain-Source On-State Resistance			3.6	5.5		
Forward Transconductance	$V_{DS} = 10V, I_{D} = 200mA$	g _{fs}	100			mS
Diode Forward Voltage	$I_S = 300 \text{mA}, V_{GS} = 0 \text{V}$	V _{SD}		0.9	1.2	V
Dynamic ^b						
Total Gate Charge	$V_{DS} = 10V, I_D = 250mA,$ $V_{GS} = 4.5V$	Q_g		0.4		nC
Input Capacitance	$V_{DS} = 25V, V_{GS} = 0V,$	C _{iss}		7.32		
Output Capacitance		C _{oss}		3.42		pF
Reverse Transfer Capacitance	f = 1.0MHz	C _{rss}		7.63		
Switching ^c						
Turn-On Delay Time	$V_{DD} = 30V, R_{G} = 10\Omega$	t _{d(on)}		25		C
Turn-Off Delay Time	$I_D = 100 \text{mA}, V_{GEN} = 10 \text{V},$	t _{d(off)}		35		nS

Notes:

- a. pulse test: PW ≤300µS, duty cycle ≤2%
 b. For DESIGN AID ONLY, not subject to production testing.
- b. Switching time is essentially independent of operating temperature.



Switching Test Circuit

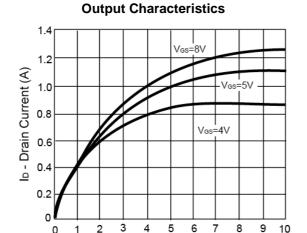
Switchin Waveforms



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Electrical Characteristics Curve (Ta = 25°C, unless otherwise noted)



1.4 1.2 lo - Drain Current (A) 1.0 0.8 0.6 0.4 0.2

Transfer Characteristics

On-Resistance vs. Drain Current

4

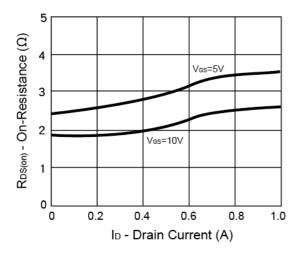
6 7 8

VDS - Drain-to-Source Voltage (V)

10

2

0



Forward Transfer Admittance vs. Drain Current

5

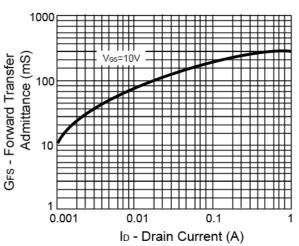
V_{GS} - Gate-to-Source Voltage (V)

6 7 8 9 10

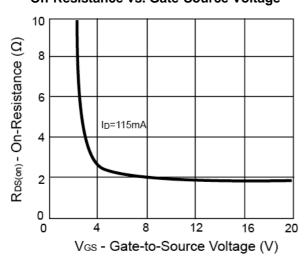
0

0

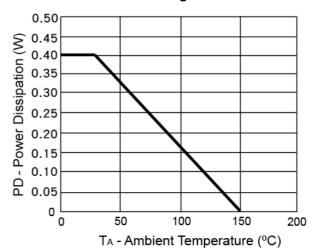
2 3 4



On-Resistance vs. Gate-Source Voltage



Power Derating Curve

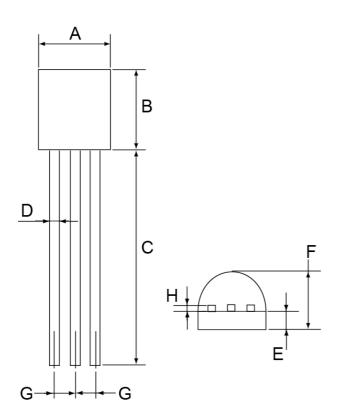








TO-92 Mechanical Drawing



TO-92 DIMENSION					
DIM	MILLIMETERS		INCHES		
	MIN	MAX	MIN	MAX	
Α	4.30	4.70	0.169	0.185	
В	4.30	4.70	0.169	0.185	
С	13.53 (typ)		0.532 (typ)		
D	0.39	0.49	0.015	0.019	
Е	1.18	1.28	0.046	0.050	
F	3.30	3.70	0.130	0.146	
G	1.27	1.31	0.050	0.051	
Н	0.33	0.43	0.013	0.017	

Marking Diagram



Y = Year Code

M = Month Code

(A=Jan, B=Feb, C=Mar, D=Apl, E=May, F=Jun, G=Jul, H=Aug,

I=Sep, J=Oct, K=Nov, L=Dec)

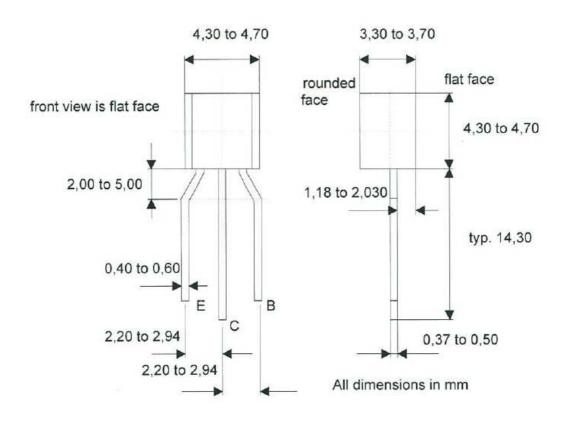
L = Lot Code



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TO-92 Ammo Pack Mechanical Drawing





TSM2N7000K 60V N-Channel MOSFET

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